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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/966,171	09/28/2001	Katsuyuki Yamada	65988 CCD	5507
7590 10/31/2007 COOPER & DUNHAM LLP			EXAMINER	
1185 Ave. of the Americas New York, NY 10036		•	ANGEBRANNDT, MARTIN J	
			ART UNIT	PAPER NUMBER
			1795	
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			MAIL DATE	DELIVERY MODE
			10/31/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	<u> </u>	Application No.	Applicant(s)				
		09/966,171	YAMADA ET AL.				
	Office Action Summary	Examiner	Art Unit				
		Martin J. Angebranndt	1795				
	The MAILING DATE of this communication app	ears on the cover sheet w	vith the correspondence address				
Period fo	ORTENED STATUTORY PERIOD FOR REPLY	/ IS SET TO EVOIDE 2 N	MONTH(S) OF THIRTY (30) DAVS				
WHIC - Exte after - If NC - Failu Any	CHEVER IS LONGER, FROM THE MAILING DANSIONS of time may be available under the provisions of 37 CFR 1.1: SIX (6) MONTHS from the mailing date of this communication. O period for reply is specified above, the maximum statutory period vere to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUN 36(a). In no event, however, may a vill apply and will expire SIX (6) MO , cause the application to become A	ICATION. reply be timely filed NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).				
Status							
1)⊠	Responsive to communication(s) filed on 8/13/	<u>′07</u> .					
2a)⊠	This action is FINAL . 2b) ☐ This	action is non-final.					
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
	closed in accordance with the practice under E	x parte Quayle, 1935 C.	D. 11, 453 O.G. 213.				
Disposit	ion of Claims						
4)⊠	4)⊠ Claim(s) <u>1-4,6-10,12-14,17-25 and 27-38</u> is/are pending in the application.						
	4a) Of the above claim(s) is/are withdrawn from consideration.						
· <u> </u>	Claim(s) is/are allowed.						
·	Claim(s) <u>1-4,6-10,12-14,17-25 and 27-38</u> is/ard	e rejected.					
•	Claim(s) is/are objected to. Claim(s) are subject to restriction and/o	r alaction requirement					
الــا(٥	cialin(s) are subject to restriction and/o	r election requirement.					
Applicat	ion Papers						
	The specification is objected to by the Examine						
10)	The drawing(s) filed on is/are: a) acc						
	Applicant may not request that any objection to the						
11)	Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Ex	·	***				
,	·	ammer. Note the attack	'				
Priority (under 35 U.S.C. § 119						
•	12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) All b) Some * c) None of:							
	 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 						
	Certified copies of the priority documents have been received in Application No Copies of the certified copies of the priority documents have been received in this National Stage						
	application from the International Bureau (PCT Rule 17.2(a)).						
* See the attached detailed Office action for a list of the certified copies not received.							
•	<i>"</i> "						
Attachmer	nt(s) ce of References Cited (PTO-892)	4) Theories	Summary (PTO-413)				
2) Notice	ce of Draftsperson's Patent Drawing Review (PTO-948)	Paper No	o(s)/Mail Date				
	mation Disclosure Statement(s) (PTO/SB/08) er No(s)/Mail Date	5) Notice of 6) Other: _	Informal Patent Application				

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1. The response of the applicant has been read and given careful consideration. Responses

to the arguments of the applicant are presented after the first rejection to which they are directed.

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2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all

obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person

such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the

manner in which the invention was made.

3. Claims 1-4,6-8,10,12,14,33 and 38 are rejected under 35 U.S.C. 103(a) as being

unpatentable over Yoshinari et al. '913, in view of Ando et al. '543 and Hisotomi et al. WO

99/38168.

Yoshinari et al. '913 in example 1 teaches a 0.6 mm (DVD) substrate with a track pitch

of 1.2 microns, a groove depths of 65 nm and width of 0.6 microns, overcoated with 170 nm of

ZnS-SiO₂, 2 nm of Cr₂O₃, a Ge₂Sb₂Te₅ recording layer, 2 nm of Cr₂O₃, 20 nm of ZnS-SiO₂ and

200 nm of Al- 1.7%Cr reflective layer and the UV recording layer, which is used with a 634 nm

laser and a relative linear velocity of 8.2 m/s. (12/55-14/7). The maximum linear velocity is

preferred to be between 6.8 and 15 m/s (10/7-17).

Ando et al. '543 disclose GeTeSb phase change optical recording media (RAM) (8/53-

58). The lead-in area is disclosed as containing embossed information including linear velocity

upon recording and erasure. (10/60-64)

Hisotomi et al. WO 99/38168 disclose GeTeSb phase change optical recording media

(RAM) (page 6). The lead-in area is disclosed as containing embossed information including

linear velocity upon recording and erasure. (paragraph bridging pages 7-8)

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It would have been obvious to modify the cited example of Yoshinari et al. '913 by including the various performance characteristics, such a optimum or uppermost recroding velocities in the lead in area of the optical disc so that the disc is used under improper conditions as discussed by described Ando et al. '543 in column 8 and Hisotomi et al. WO 99/38168 on pages 6-8 as this is considered conventional to provide this information to the readout/recording system. The position of the examiner is that the optimum or maximum recording linear velocities are provided in the lead in area and that the media operating in the range of 6.8 to 12 m/s would inherently have uppermost recrystallization velocities in the 12-24 m/s range for at least some specific conditions of laser power and wavelength.

The previous rejection sdhad relies upon references which used slower responding media. The applicant argues that 16X, 20X and 24X recording velocities, but the specification also teaches example 2, which has a disloctaiton velocity of 14.4 m/s and a maximum recording velocity of 8.44 m/s. Furthermore the claims fail to specify the conditions for the determination of the uppermost recrystalization velocity. Clearly this leaves the claims embracing a variety of conditions for this, which allows the rejection of the claims. This position is supported by the prepub of the instant specification at [0018] which states that the dislocation velocity is dependent upon the track pitch, laser wavelgnth, NA and laser power.

4. Claims 1-4,6-8,10,12-14,33 and 38 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yasuda et al. '788, in view of Ando et al. '543 and Hisotomi et al. WO 99/38168.

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Yasuda et al. '788 teach in example 5, a recording medium with a pitch of 0.9 microns and operating at 10 m/s. The recording medium structure is a 20 nm Al film, a ZnS-SiO₂ layer, a SiN film. A GeTeSbN recording layer, a SiN layer, a ZnS-SiO₂ layer and a Au-Co alloy layer and the second recording laminate (31/50-32/55). The recording layer compositions can be AgInSbTe recording layers and may have additives including Ga and the like (12/16-50). The recording medium substrate can be 0.3 to 1.2 mm thick, and is grooved. (15/30-46). See also example 4, which operates at 10 m/s. (30/50-31/46). The crystallization improvement layers are disclosed including Si, SiC and the like (24/46-56).

It would have been obvious to modify the cited examples of Yasuda et al. '788 by including the various performance characteristics, such a optimum or uppermost recroding velocities in the lead in area of the optical disc so that the disc is used under improper conditions as discussed by described Ando et al. '543 in column 8 and Hisotomi et al. WO 99/38168 on pages 6-8 as this is considered conventional to provide this information to the readout/recording system. The position of the examiner is that the optimum or maximum recording linear velocities are provided in the lead in area and that the media operating at 10 m/s would inherently have uppermost recrystallization velocities in the 12-24 m/s range for at least some specific conditions of laser power and wavelength.

5. Claims 1-4,6-8,10,12-14,33 and 38 are rejected under 35 U.S.C. 103(a) as being unpatentable over Uno et al. '135, in view of Ando et al. '543 and Hisotomi et al. WO 99/38168.

Uno et al. '135 teach in example 1, a recording medium with a pitch of 1.20 microns, groove widths of 0.6 microns, operating at 12 m/s. The recording medium structure is Au layer, a ZnS-SiO₂ layer, a SiC-SiN layer, a GeTeSb recording layer, a SiC-SiN layer (13-21-14/51).

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Useful optical roccirding layers include GeSbTe, AgInSbTe, and the like (8/7-40). Media 1,8 and 11 in tables 1 and 2 have the best performance at 12 m/s.

It would have been obvious to modify the cited examples of Yasuda et al. '788 by including the various performance characteristics, such a optimum or uppermost recroding velocities in the lead in area of the optical disc so that the disc is used under improper conditions as discussed by described Ando et al. '543 in column 8 and Hisotomi et al. WO 99/38168 on pages 6-8 as this is considered conventional to provide this information to the readout/recording system. The position of the examiner is that the optimum or maximum recording linear velocities are provided in the lead in area and that the media operating at 12 m/s would inherently have uppermost recrystallization velocities in the 12-24 m/s range for at least some specific conditions of laser power and wavelength.

6. Claims 1-4,6-10,12-14,17-25 and 27-38 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yasuda et al. '788 or Uno et al. '135, in view of Ando et al. '543 and Hisotomi et al. WO 99/38168, further in view of Nobukuni et al. EP 1056077.

Nobukuni et al. EP 1056077 in example 9 has a polycarbonate substrate, 100 nm ZnS-SiO₂ layer, a 20 nm recording Ga₅Ge₅Sb₆₈Te₂₂ layer, a 40 nm ZnS-SiO₂ layer, a 250 nm reflective layer and a protective layer which is embraced by the language of claim 27 and is used at 10X recording velocties. [0464]. The addition of various materials including In, Ga, Si, Sn, Pb, Pd, Pt, Zn, Au, Ag, Zr, Hf, V, Nb, Ta, Cr, Co, Bi, N,O,S and rare earths as impurities to improve the performance and the reliability of the recording layer is disclosed [0073-0074]. Groove depths can be 30-45 nm. [0149]. The groove widths can be 0.4-0.6 microns [0153]. Example/embodiment 5 teaches a In₈Ag₅Sb₆₈Te₂₂ recording layer.

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To address other embodiment bounded by the claims, but not rendered obvious above, the examiner cites Nobukuni et al. EP 1056077 and holds that it would have been obvious to modify the media resulting from the combination of (Yasuda et al. '788 or Uno et al. '135), Ando et al. '543 and Hisotomi et al. WO 99/38168 by using other recording medium compositions and/or substrate thicknesses such as those disclosed by Nobukuni et al. EP 1056077, based upon the similar disclosures within Yasuda et al. '788. Further it would have been obvious to use other track widths and depths disclosed by Nobukuni et al. EP 1056077 with the smaller track pitches taught by Yasuda et al. '788 to increase the information content while maintaining a reasonable expectation of success of forming a useful optical recording medium based upon the disclosure of utility within Nobukuni et al. EP 1056077.

7. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

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8. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Martin J. Angebranndt whose telephone number is 571-272-1378.

The examiner can normally be reached on Monday-Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Mark Huff can be reached on 571-272-1385. The fax phone number for the

organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

applications is available through Private PAIR only. For more information about the PAIR

system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

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like assistance from a USPTO Customer Service Representative or access to the automated

information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Martin J Angebranndt

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Primary Examiner

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10/29/2007